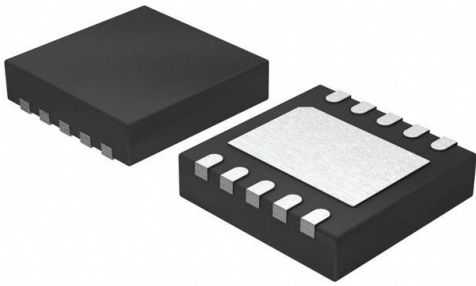


PI3USB221EZWEX Datasheet

www.digi-electronics.com



<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	PI3USB221EZWEX-DG
Manufacturer	Diodes Incorporated
Manufacturer Product Number	PI3USB221EZWEX
Description	IC USB2 SWITCH 3V UDFN3030-10
Detailed Description	USB Switch IC 1 Channel 10-UDFN (3x3)



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.

Purchase and inquiry

Manufacturer Product Number:

PI3USB221EZWEX

Series:

-

Applications:

USB

Switch Circuit:

SPDT

On-State Resistance (Max):

60hm

Voltage - Supply, Dual (V±):

-

Features:

Bi-Directional, USB 2.0

Mounting Type:

Surface Mount

Supplier Device Package:

10-UDFN (3x3)

Manufacturer:

Diodes Incorporated

Product Status:

Active

Multiplexer/Demultiplexer Circuit:

2:1

Number of Channels:

1

Voltage - Supply, Single (V+):

2.3V ~ 3.6V

-3db Bandwidth:

1.1GHz

Operating Temperature:

-40°C ~ 85°C

Package / Case:

10-UDFN Exposed Pad

Base Product Number:

PI3USB221

Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8542.39.0001

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99



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PI3USB221E

High-Speed USB2.0 1:2 Multiplexer/DeMultiplexer Switch with Signal Enable

Features

- V_{DD} Operation at 2.5V and 3.3V
- $V_{I/O}$ Accepts Signals up to 5.5V
- 1.8-V Compatible Control-Pin Inputs
- Low-Power Mode When \overline{OE} Is Disabled (2 μ A)
- $r_{ON} = 6\Omega$ Maximum
- $\Delta r_{ON} = 0.2\Omega$ Typical
- $C_{io(on)} = 4pF$ Typical
- Support Over Voltage Protection
- Low Power Consumption (50 μ A Maximum)
- ESD Performance
- IO Pins
 - 12KV HBM
 - 1KV CDM
 - +/-8KV contact Discharge (IEC61000-4-2)
 - VDD, GND, S, \overline{OE} Pins
 - 4KV HBM
 - 1KV CDM
- High Bandwidth (1.6 GHz Typical)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](#) or your local Diodes representative.
<https://www.diodes.com/quality/product-definitions/>
- Packaging (Pb-free & Green):
 - 10-contact, UDFN (ZW10)
 - 10-contact, UQFN (ZUA10)

Truth Table

S	\overline{OE}	Function
X	H	Disconnect
L	L	D = 1D
H	L	D = 2D

Description

The PI3USB221E is a high-bandwidth switch specially designed for the switching of high-speed USB 2.0 signals in handset and consumer applications, such as cell phones, digital cameras, and notebooks with hubs or controllers with limited USB I/Os.

The wide bandwidth (1.1 GHz) of this switch allows signals to pass with minimum edge and phase distortion. The device multiplexes differential outputs from a USB host device to one of two corresponding outputs. The switch is bidirectional and offers little or no attenuation of the high-speed signals at the outputs.

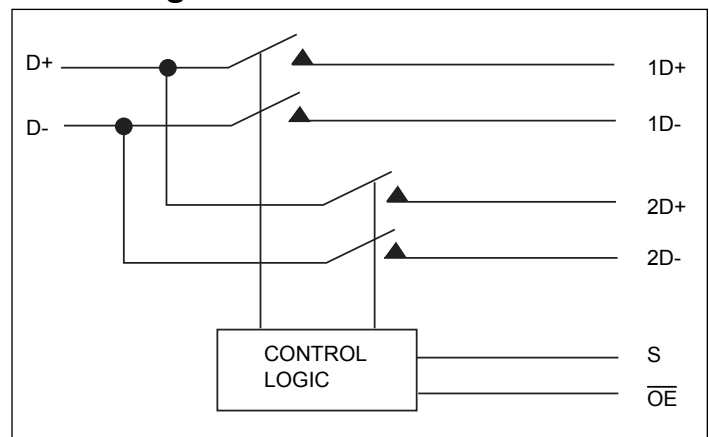
It is designed for low bit-to-bit skew and high channel-to-channel noise isolation, and is compatible with various standards, such as high-speed USB 2.0 (480 Mbps).

The PI3USB221E offer over voltage protection for the D+/D- pins as per the USB 2.0 specification. With the chip power on or off if D+/D- pins are shorted to VBus (5V+/-5%), a less than 3.8V (typical) signal will transmit through 1D+/1D- and 2D+/2D- output.

Applications

- Routes Signals for USB 1.0, 1.1, and 2.0
- Mobile Industry Processor Interface (MIPI) Signal Routing

Block Diagram



Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

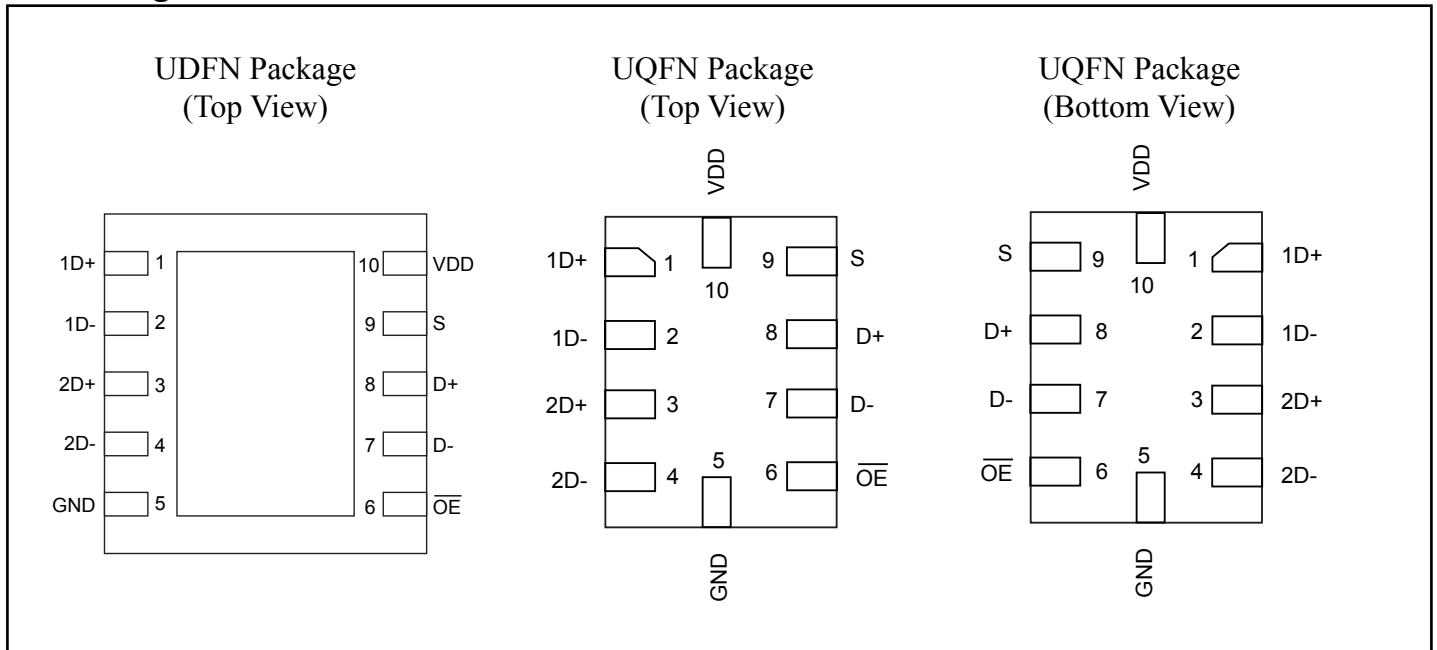


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PI3USB221E

Pin Configuration



Pin Description

Name	Description
$\overline{\text{OE}}$	Active LOW, Output enable
S	Select input
D	COM port
nD	I/O for USB data path (port 1 and port 2)



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PI3USB221E

Absolute Maximum Ratings⁽¹⁾

Over operating free-air temperature range (unless otherwise noted)

V _{DD} Supply Voltage Range	-0.5V to 4.6V
V _{IN} Control Input Voltage Range ^(2, 3)	-0.5V to 5.5V
V _{I/O} Switch I/O Voltage Range ^(2, 3, 4)	-0.5V to 5.5V
I _{IK} Control Input Clamp Current (V _{IN} < 0)	-50mA
I _{I/OK} I/O Port Clamp Current (V _{I/O} < 0)	-50mA
I _{I/O} ON-state Switch Current ⁽⁵⁾	±120mA
Continuous Current through V _{DD} or GND	±100mA
θ _{JA} Package Thermal Impedance	
TLLGA Package	48.7°C/W
TDFN Package	243°C/W
T _{stg} Storage Temperature Range	-65 to 150°C
T _j Junction Temperature	125°C

Notes:

- Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- All voltages are with respect to ground, unless otherwise specified.
- The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- VI and VO are used to denote specific conditions for VI/O.
- II and IO are used to denote specific conditions for II/O.
- The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions⁽¹⁾

Symbol	Description	Parameter	Min.	Max.	Unit
V _{DD}	Supply voltage		2.3	3.6	V
V _{IH}	High-level control input voltage	V _{DD} = 2.3 V to 2.7 V	1.3	-	
		V _{DD} = 2.7 V to 3.6 V	1.4	-	
V _{IL}	Low-level control input voltage	V _{DD} = 2.3 V to 2.7 V		0.6	
		V _{DD} = 2.7 V to 3.6 V		0.6	
V _{I/O}	Data input/output voltage		0	4.6	
T _A	Operating free-air temperature		-40	85	°C

Note:

- All unused control inputs of the device must be held at V_{DD} or GND to ensure proper device operation.



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PI3USB221E

Electrical Characteristics

Over operating free-air temperature range (unless otherwise noted)

Parameter	Testing Conditions	Min.	Typ.	Max.	Unit	
V_{IK}	$V_{DD} = 3.6V, 2.7V, I_I = -18 \text{ mA}$			-1.2	V	
I_{IN}	Control Inputs $V_{DD} = 3.6V, 2.7V, 0V, V_{IN} = 0V \text{ to } 3.6V$			± 1	μA	
$I_{OZ}^{(3)}$	$V_{DD} = 3.6V, 2.7V, V_{IN} = V_{DD} \text{ or } GND,$ $V_O = 0V \text{ to } 3.6V, V_I = 0V, \text{ Switch OFF}$			± 1		
$I_{(OFF)}$	$V_{DD} = 0V$	$V_{I/O} = 0V \text{ to } 3.6V$		± 2		
		$V_{I/O} = 0 \text{ to } 2.7V$		± 1		
I_{CC}	$V_{DD} = 3.6V, 2.7V, V_{IN} = V_{DD} \text{ or } GND,$ $I_{I/O} = 0 \text{ V, Switch ON or OFF}$		25	50		
I_{CC} (low power mode)	$V_{DD} = 3.6V, 2.7V, V_{IN} = V_{DD} \text{ or } GND,$ Switch disabled, (\overline{OE} in high state)			4		
$D I_{CC}^{(4)}$	Control Inputs	$V_{DD} = 2.7V, S$ sweeps from 1.4V to 3.3V, $OE/ = 0V$		15		
		$V_{DD} = 2.7V, OE/$ sweeps from 1.4V to 3.3V, $S = 0V$		0.75		
C_{IN}	Control Inputs $V_{DD} = 3.3V, 2.5V, V_{IN} = 3.3V \text{ or } 0V$		1	2	pF	
$C_{iO(OFF)}$	$V_{DD} = 3.3V, 2.5V, V_{IN} = 3.3V \text{ or } 0V, \text{ Switch OFF}$		2	3		
$C_{iO(ON)}$	$V_{DD} = 3.3V, 2.5V, V_{IN} = 3.3V \text{ or } 0V, \text{ Switch ON}$		4	6		
$r_{ON}^{(5)}$	$V_{DD} = 3V, 2.3V$	$V_I = 0V, I_O = 30 \text{ mA}$		4		
		$V_I = 2.4V, I_O = -15 \text{ mA}$		6		
$D r_{ON}^{(6)}$	$V_{DD} = 3V, 2.3V$	$V_I = 0V, I_O = 30 \text{ mA}$		0.2		
		$V_I = 1.7V, I_O = -15 \text{ mA}$		0.2		
$r_{ON(Flat)}$	$V_{DD} = 3V, 2.3V$	$V_I = 0V, I_O = 30 \text{ mA}$		1		
		$V_I = 1.7V, I_O = -15 \text{ mA}$		1		
V_{pass}	$V_{DD} = 2.5 - 3.3V$	$V_{IN} > 3.8V, I_O = 10\mu A$	2.8	3.8	4.2	V

Notes:

- V_{IN} and I_{IN} refer to control inputs. V_I , V_O , I_I , and I_O refer to data pins.
- All typical values are at $V_{DD} = 3.3 \text{ V}$ (unless otherwise noted), $T_A = 25^\circ C$.
- For I/O ports, the parameter IOZ includes the input leakage current.
- This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{DD} or GND.
- Measured by the voltage drop between the input and output terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two terminals.
- Dron is delta Ron between channels

Dynamic Electrical Characteristics

Over operating range, $T_A = -40^\circ C \text{ to } 85^\circ C, V_{DD} = 3.3 \text{ V} \pm 10\%, GND = 0V$

Symbol	Parameter	Test Conditions	Typ. ⁽¹⁾	Unit
X_{TALK}	Crosstalk	$R_L = 50\Omega, f = 250 \text{ MHz}$	-40	dB
O_{IRR}	OFF isolation	$R_L = 50\Omega, f = 250 \text{ MHz}$	-41	
BW	Bandwidth (-3 dB)	$R_L = 50\Omega$	1.6	GHz

Note:

- For Max or Min conditions, use the appropriate value specified under Electrical Characteristics for the applicable device type.



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PI3USB221E

Switching Characteristics

Over operating range, $T_A = -40^{\circ}\text{C}$ to 85°C , $V_{DD} = 3.3\text{ V} \pm 10\%$, $\text{GND} = 0\text{V}$

Symbol	Parameter	Min.	Typ. ⁽¹⁾	Max.	Unit
t_{pd}	Propagation Delay ^(2,3)		0.25		ns
t_{ON}	Line enable time	S to D, nD		125	
		$\overline{\text{OE}}$ to D, nD		100	
t_{OFF}	Line disable time	S to D, nD		12	
		$\overline{\text{OE}}$ to D, nD		12	
$t_{SK(O)}$	Output skew between center port to any other port ⁽²⁾		0.1	0.2	
$t_{SK(P)}$	Skew between opposite transitions of the same output ($t_{PHL} - t_{PLH}$) ⁽²⁾		0.1	0.2	
t_{VPASS}	OVP response time		53		ns

Notes:

1. For Max or Min conditions, use the appropriate value specified under Electrical Characteristics for the applicable device type.
2. Specified by design
3. The switch contributes no propagational delay other than the RC delay of the on resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.25 ns for 10-pF load. Since this time constant is much smaller than the rise/fall times of typical driving signals, it adds very little propagational delay to the system. Propagational delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interactions with the load on the driven side.

Application Information

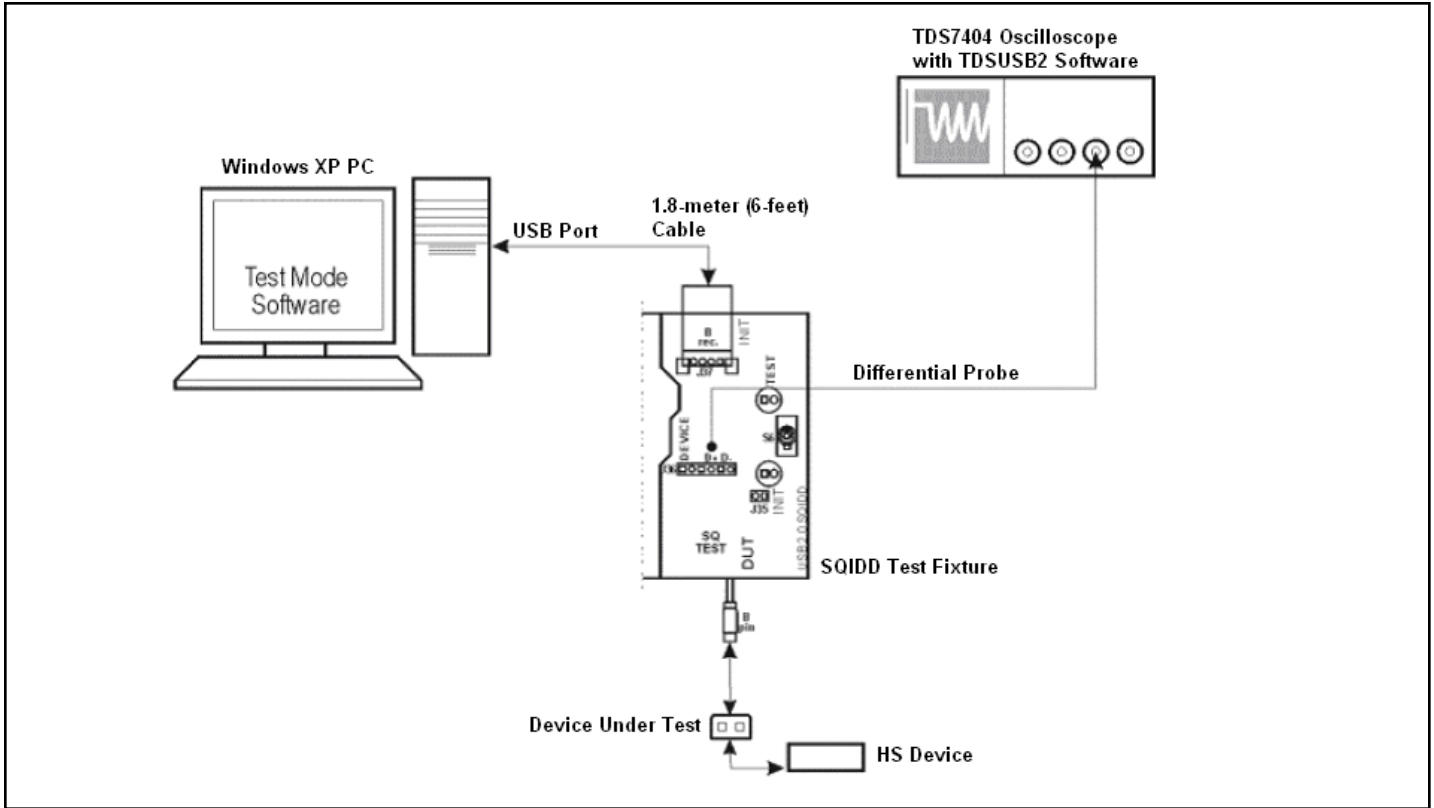
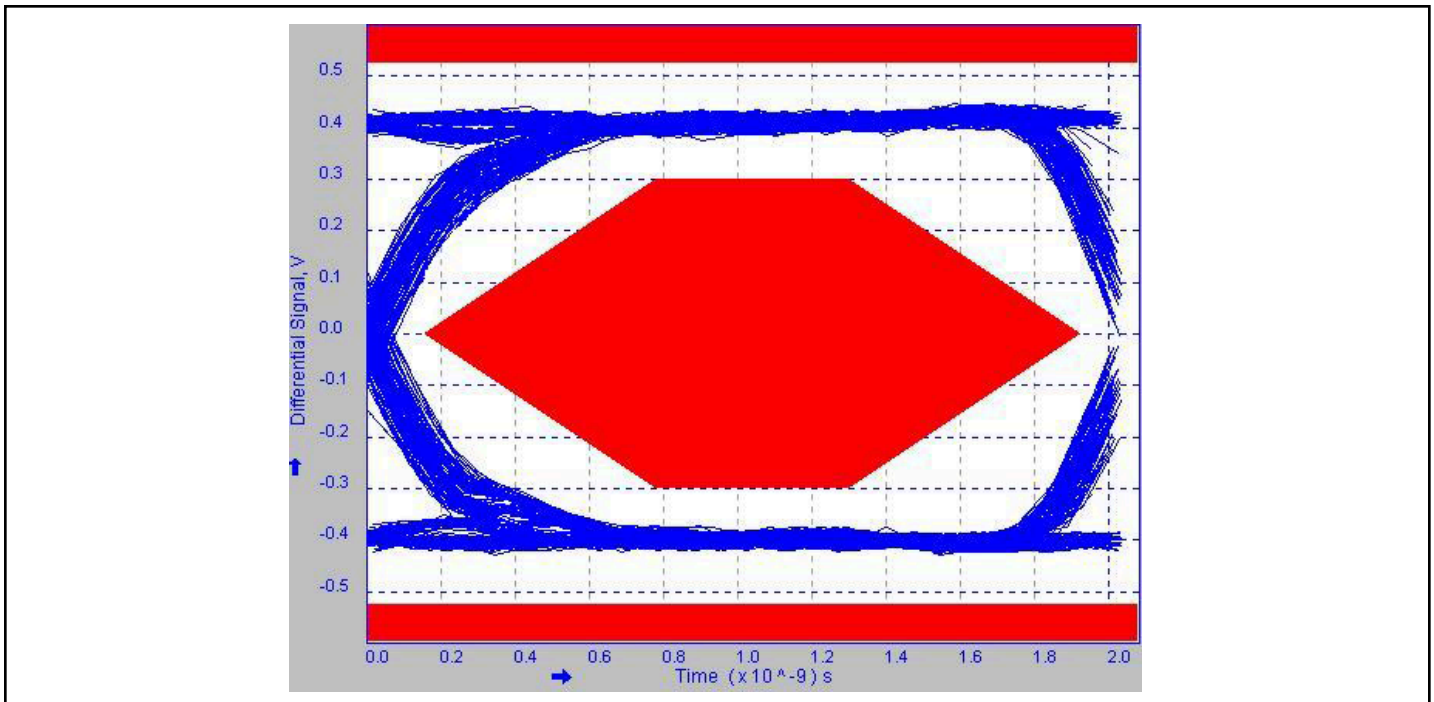


Figure 1: HS Eye Test Setup

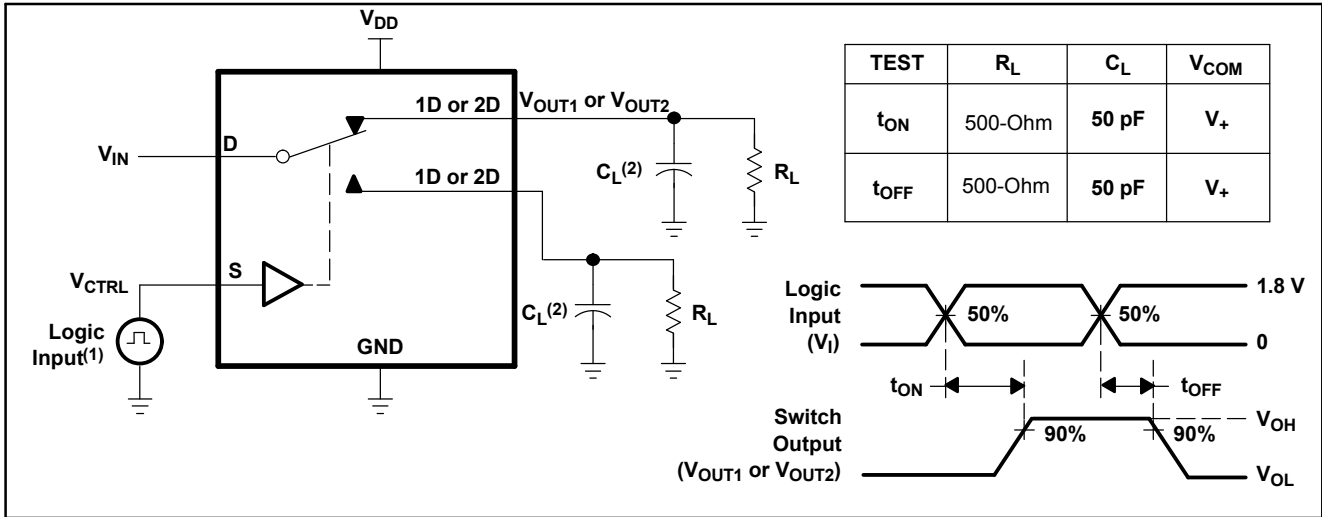
Test Result



Test Result: High-speed, Up-stream, Near-end Eye of PI3USB221E

PI3USB221E

Parameter Measurement Information



- (1) All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50-Ohm, t_r < 5 ns, t_f < 5 ns.
- (2) C_L includes probe and jig capacitance.

Figure 2. Turn-On (t_{ON}) and Turn-Off Time (t_{OFF})

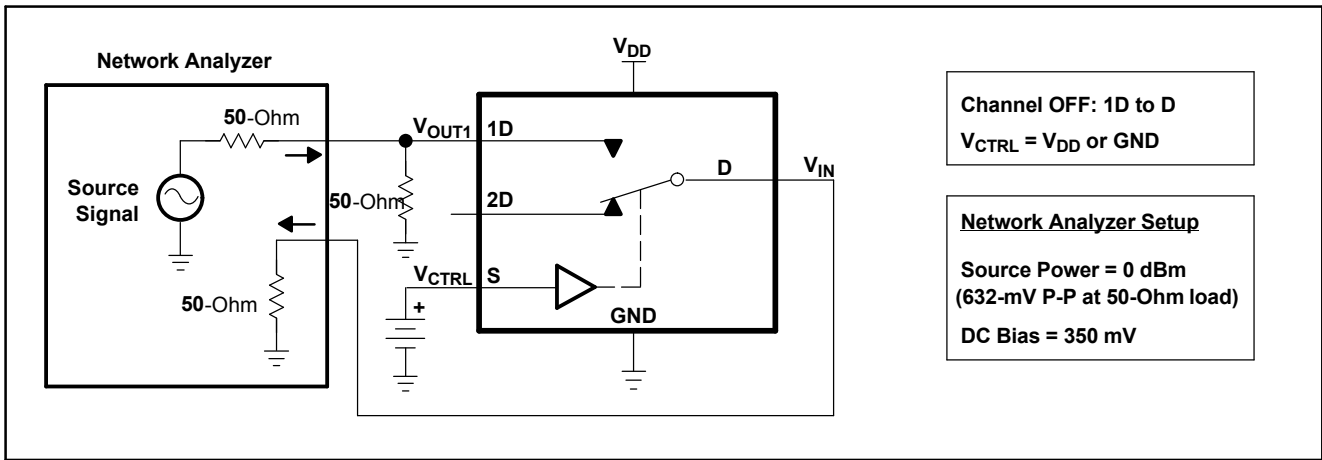


Figure 3. OFF Isolation (O_{ISO})

PI3USB221E

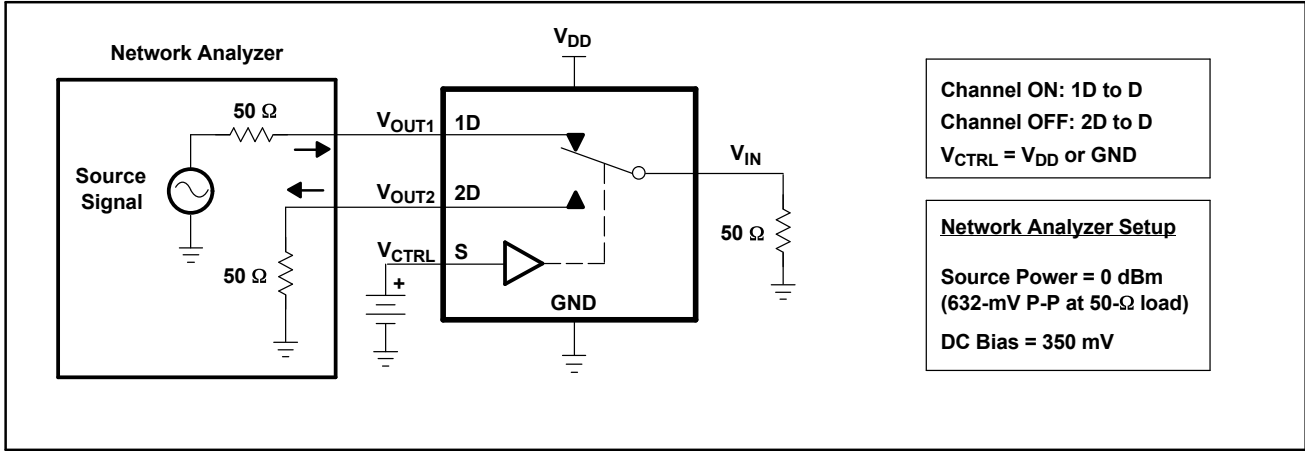


Figure 4. Crosstalk (X_{TALK})

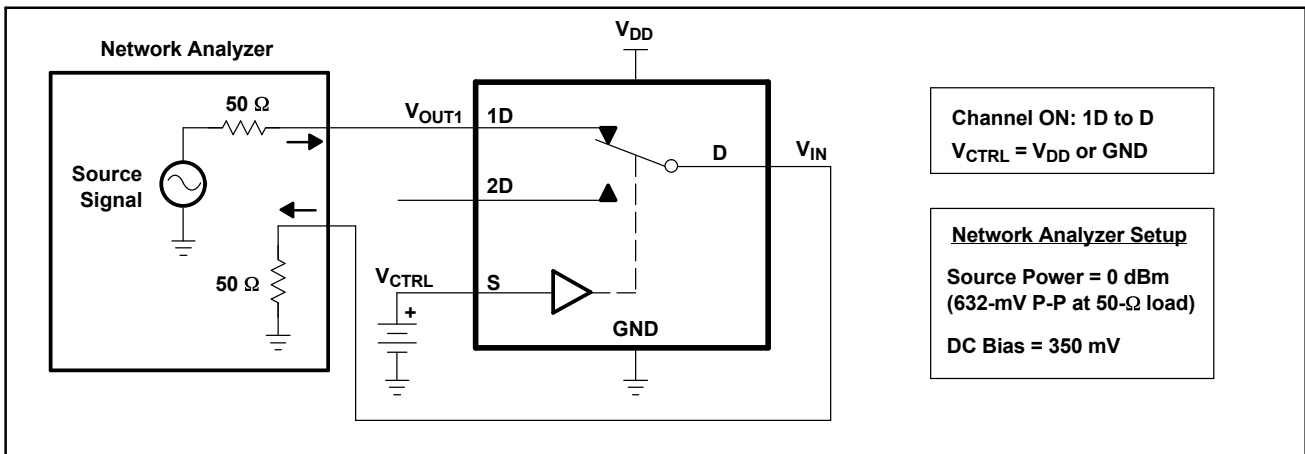


Figure 5. Bandwidth (BW)

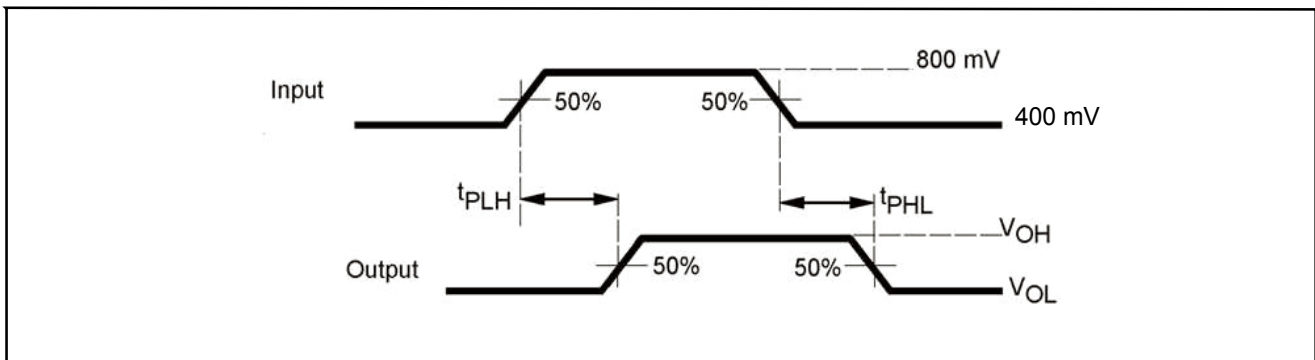


Figure 6. Propagation Delay

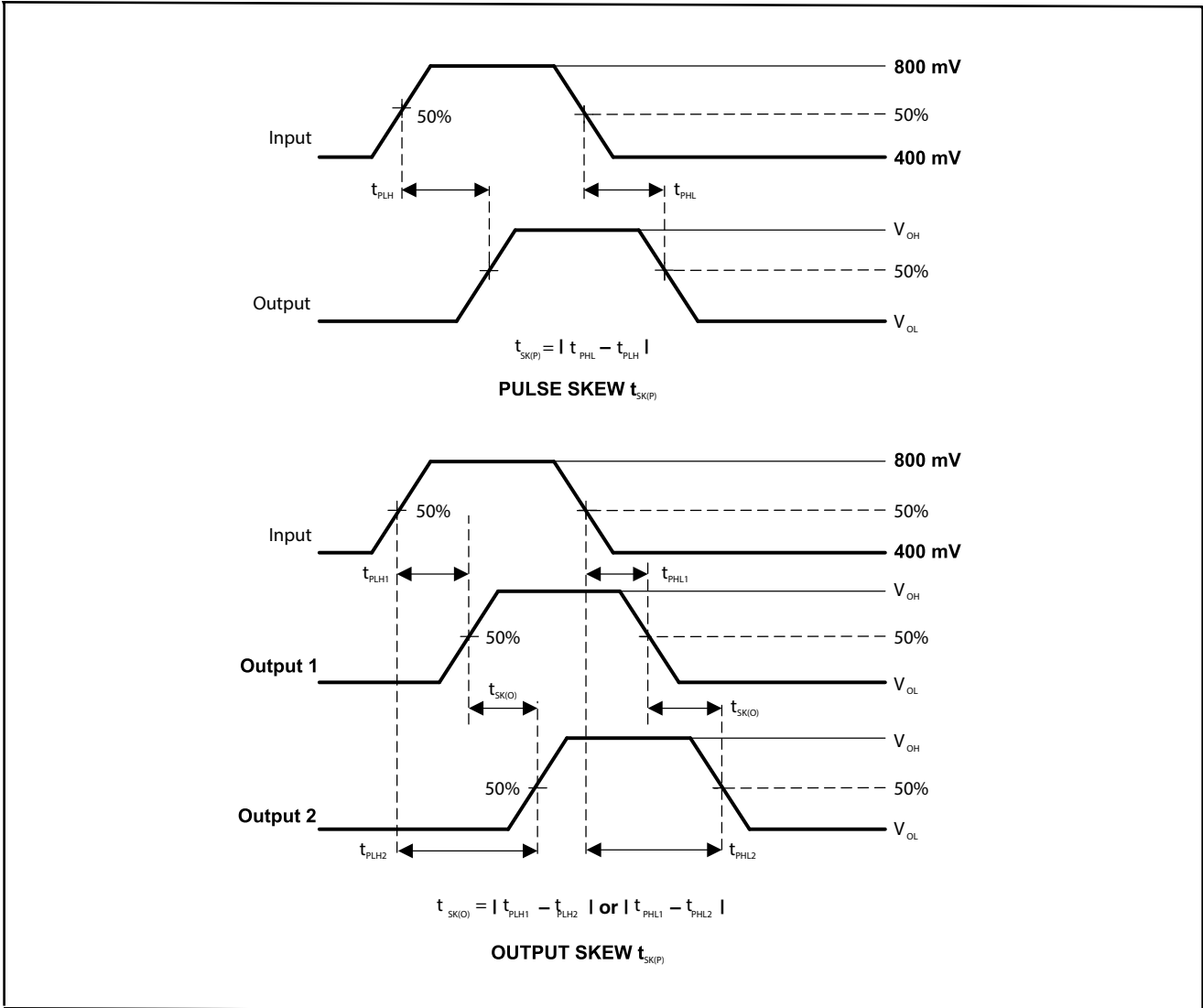


Figure 7. Skew Test

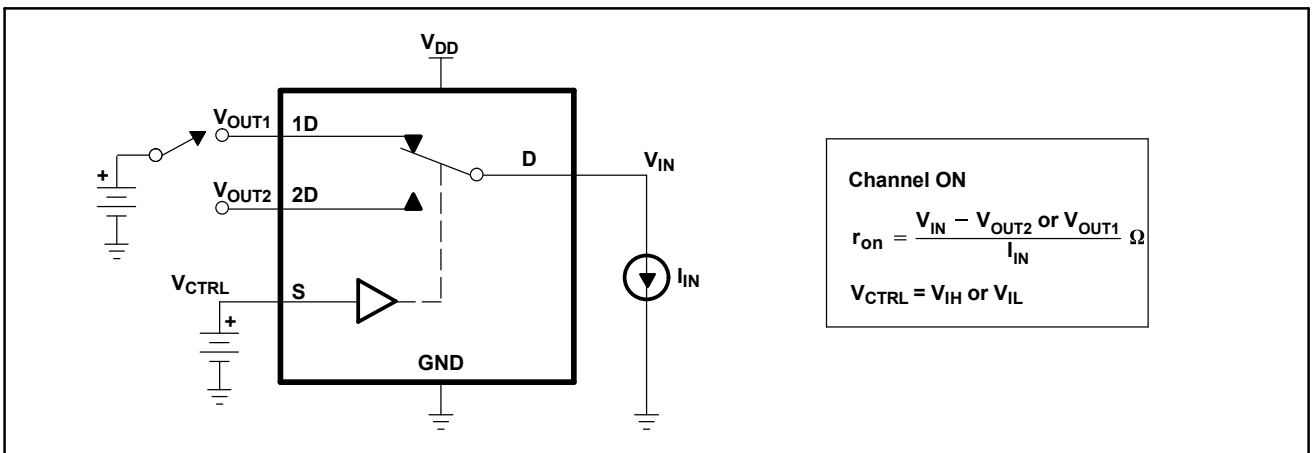


Figure 8. ON-State Resistance (r_{on})



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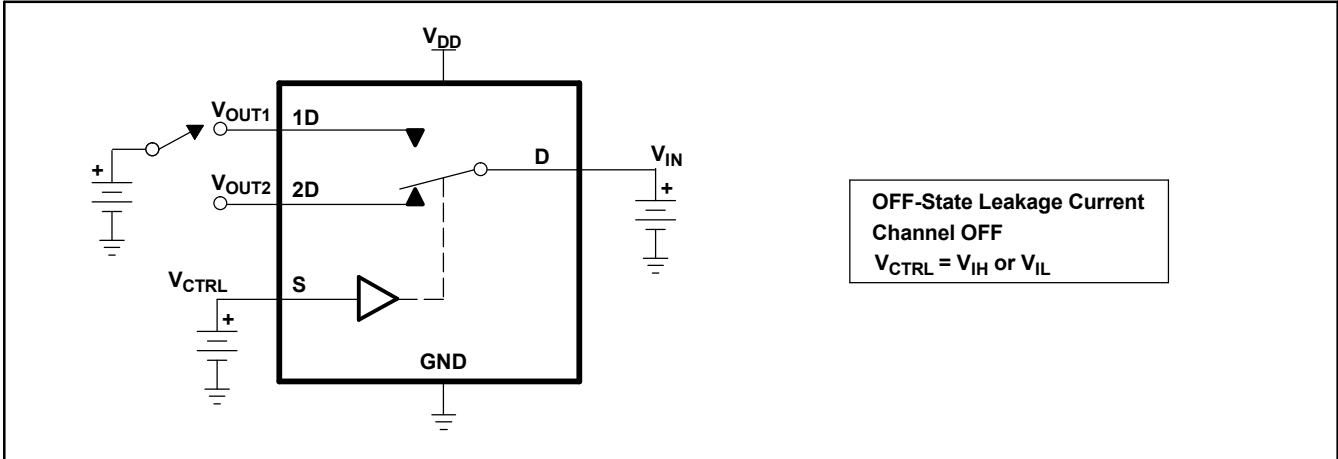


Figure 9. OFF-State Leakage Current

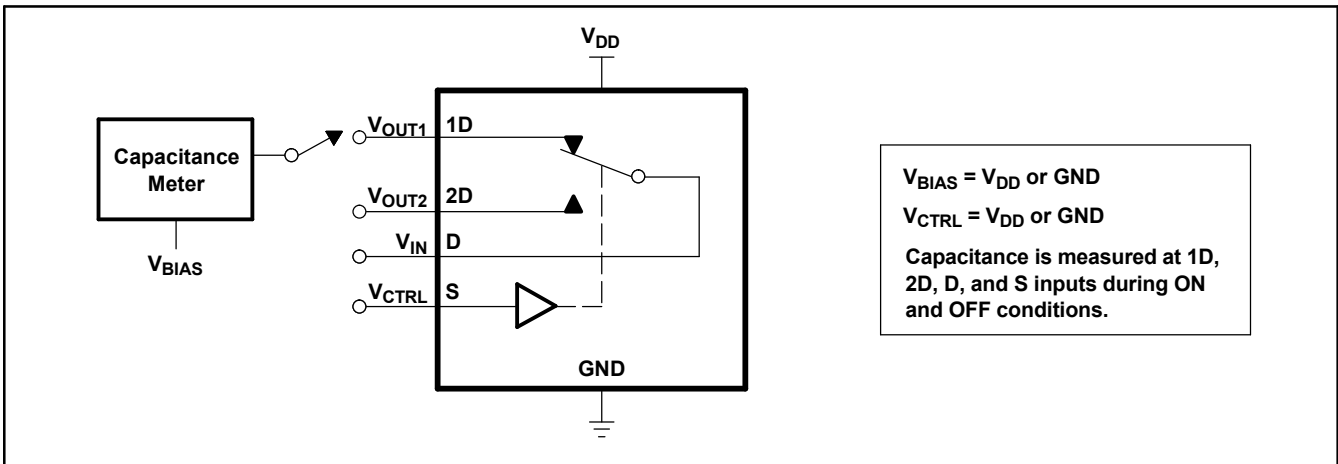
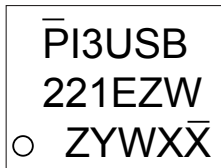


Figure 10. Capacitance

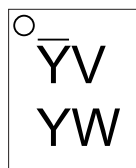
Part Marking

ZW Package



Z : Die Rev
Y : Year
W : Workweek
1st X: Assembly Code
2nd X: Fab Code

ZUA Package



Y : Shorten Year Code
W : Shorten Workweek Code



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PI3USB221E

Packaging Mechanical: 10-UQFN (ZUA)

TOP VIEW

BOTTOM VIEW

RECOMMENDED LAND PATTERN(unit:mm)

SIDE VIEW

PKG. DIMENSIONS(MM)			
SYMBOL	Min	NOM	Max
A	0.50	0.60	0.65
A1	0.00	0.02	0.05
A3	0.15 REF		
D	1.45	1.50	1.55
E	1.95	2.00	2.05
b	0.20	0.25	0.30
b1	0.15	0.20	0.25
b2	0.25	0.30	0.35
e	0.50 BSC		
L	0.25	0.35	0.45
L1	0.30	0.40	0.50

Notes:
1. Ref: JEDEC MO-288B.

DATE: 01/06/17

DESCRIPTION: 10-Pin, UQFN, 1.5X2.0	
PACKAGE CODE: ZUA(ZUA10)	
DOCUMENT CONTROL#: PD-2220	REVISION: --

17-0002



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PI3USB221E

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